Current Mode PWM Control Circuit

The CS52843 provides all the necessary features to implement off-line fixed frequency current-mode control with a minimum number of external components.

The CS52843 incorporates a new precision temperature–controlled oscillator to minimize variations in frequency. An undervoltage lockout ensures that V_{REF} is stabilized before the output stage is enabled. In the CS52843 turn on is at 8.4 V and turn off at 7.6 V.

Other features include low start-up current, pulse-by-pulse current limiting, and a high-current totem pole output for driving capacitive loads, such as gate of a power MOSFET. The output is low in the off state, consistent with N-channel devices.

Features

- Optimized for Off-Line Control
- Internally Temperature Compensated Oscillator
- V_{REF} Stabilized before Output Stage is Enabled
- Very Low Start-Up Current 300 µA (typ)
- Pulse-by-Pulse Current Limiting
- Improved Undervoltage Lockout
- Double Pulse Suppression
- 2.0% 5.0 Volt Reference
- High Current Totem Pole Output



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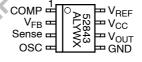


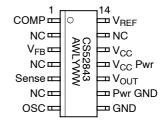
SO-8 D SUFFIX CASE 751



SO-14 D SUFFIX CASE 751A

PIN CONNECTIONS AND MARKING DIAGRAMS





A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
CS52843ED8	SO-8	95 Units/Rail
CS52843EDR8	SO-8	2500 Tape & Reel
CS52843ED14	SO-14	55 Units/Rail
CS52843EDR14	SO-14	2500 Tape & Ree

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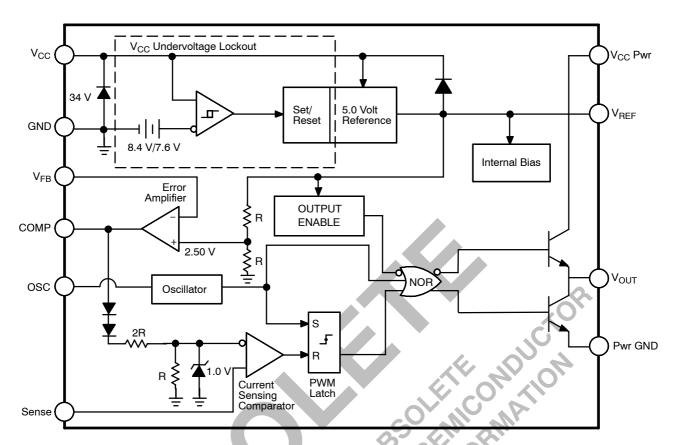


Figure 1. Block Diagram

MAXIMUM RATINGS*

Rating	Value	Unit
Supply Voltage (I _{CC} < 30 mA)	Self Limiting	1
Supply Voltage (Low Impedance Source)	30	V
Output Current	±1.0	Α
Output Energy (Capacitive Load)	5.0	μJ
Analog Inputs (V _{FB} , V _{SENSE})	-0.3 to 5.5	V
Error Amp Output Sink Current	10	mA
Lead Temperature Soldering: Reflow: (SMD styles only) (Note 1)	230 peak	°C

^{1. 60} second maximum above 183°C.

^{*}The maximum package power dissipation must be observed.

ELECTRICAL CHARACTERISTICS $(-40^{\circ}C \le T_{A} \le 85^{\circ}C; V_{CC} = 15 \text{ V (Note 2.)}; R_{T} = 680 \Omega; C_{T} = 0.022 \mu\text{F for triangle mode, } R_{T} = 10 \text{ k}\Omega; C_{T} = 3.3 \text{ nF sawtooth mode; unless otherwise specified.)}$

Parameter Test Conditions		Min	Тур	Max	Unit	
Reference Section						
Output Voltage	T _J = 25°C, I _{REF} = 1.0 mA	4.9	5.0	5.1	V	
Line Regulation	Line Regulation 12 ≤[V _{CC} ≤ 25 V		6.0	20	mV	
Load Regulation	1.0 ≤ I _{REF} ≤ 20 mA	-	6.0	25	mV	
Temperature Stability	Note 2.	-	0.2	0.4	mV/°C	
Total Output Variation	Line, Load, Temp. Note 2.	4.82	_	5.18	V	
Output Noise Voltage	10 Hz ≤ f ≤ 10 kHz, T _J = 25°C, Note 2.	-	50	-	μV	
Long Term Stability	T _A = 125°C, 1000 Hrs. Note 2.	-	5.0	25	mV	
Output Short Circuit	T _A = 25°C	-30	-100	-180	mA	
Oscillator Section				0		
Initial Accuracy	Sawtooth Mode, T _J = 25°C, Note 2. Triangle Mode, T _J = 25°C	47 44	52 52	57 60	kHz kHz	
Voltage Stability	12 ≤[V _{CC} ≤ 25 V	-	0.2	1.0	%	
Temperature Stability	Sawtooth Mode $T_{MIN} \le T_A \le T_{MAX}$ Triangle Mode $T_{MIN} \le T_A \le T_{MAX}$, Note 2.	VN	5.0 8.0	- -	% %	
Amplitude	V _{OSC} (peak to peak)	69	1.7	-	V	
Discharge Current	$T_{J} = 25^{\circ}C$ $T_{MIN} \le T_{A} \le T_{MAX}$	7.3 6.8	8.3 -	9.3 9.8	mA mA	
Error Amp Section	0, 3,	O,				
Input Voltage	V _{COMP} = 2.5 V	2.42	2.50	2.58	V	
Input Bias Current	V _{FB} = 0 V	-	-0.3	-2.0	μΑ	
Avol	2.0 ≤[V _{OUT} ≤ 4.0 V	65	90	-	dB	
Unity Gain Bandwidth	Note 2.	0.7	1.0	-	MHz	
PSRR	12 ≤[V _{CC} ≤ 25 V	60	70	-	dB	
Output Sink Current	$V_{FB} = 2.7 \text{ V}, V_{COMP} = 1.1 \text{ V}$	2.0	6.0	-	mA	
Output Source Current	V _{FB} = 2.3 V, V _{COMP} = 5.0 V	-0.5	-0.8	-	mA	
V _{OUT} HIGH	V_{FB} = 2.3 V, R_L = 15 k Ω to GND	5.0	6.0	_	V	
V _{OUT} LOW	V_{FB} = 2.7 V, R_L = 15 k Ω to V_{REF}	-	0.7	1.1	V	
Current Sense Section						
Gain	Notes 3 & 4.	2.85	3.0	3.15	V/V	
Maximum Input Signal	V _{COMP} = 5.0 V, Note 3.	0.9	1.0	1.1	V	
PSRR	12 ≤[V _{CC} ≤ 25 V, Note 3.	-	70	-	dB	
Input Bias Current	V _{SENSE} = 0 V	-	-2.0	-10	μΑ	
Delay to Output	T _J = 25°C, Note 2.	-	150	300	ns	

^{2.} These parameters, although guaranteed, are not 100% tested in production.

4. Gain defined as:
$$A = \frac{\Delta V_{COMP}}{\Delta V_{SENSE}}$$
; $0 \le V_{SENSE} \le 0.8 \text{ V}$

^{3.} Parameter measured at a trip point of latch with V_{FB} = 0.

ELECTRICAL CHARACTERISTICS (continued) ($-40^{\circ}C \le T_{A} \le 85^{\circ}C$; $V_{CC} = 15 \text{ V (Note 2.)}$; $R_{T} = 680 \Omega$; $C_{T} \ne 0.022 \mu F$ for triangle mode, $R_{T} = 10 \text{ k}\Omega$; $C_{T} \ne 3.3 \text{ nF}$ sawtooth mode; unless otherwise specified.)

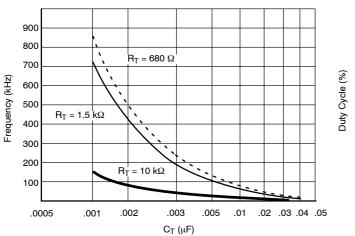
Parameter	Test Conditions	Min	Тур	Max	Unit
Output Section					
Output Low Level	I _{SINK} = 20 mA I _{SINK} = 200 mA		0.1 1.5	0.4 2.2	V V
Output High Level	I _{SOURCE} = 20 mA I _{SOURCE} = 200 mA	13 12	13.5 13.5	- -	V V
Rise Time	T _J = 25°C, C _L = 1.0 nF, Note 5.	-	50	150	ns
Fall Time	T _J = 25°C, C _L = 1.0 nF, Note 5.	-	50	150	ns
Output Leakage	UVLO Active V _{OUT} = 0	-	-0.01	-10	μΑ
Total Standby Current					
Start-Up Current	-		300	500	μА
Operating Supply Current	$V_{FB} = V_{SENSE} = 0 \text{ V}, R_T = 10 \text{ k}\Omega; C_T + 3.3 \text{ nF}$	-	11	17	mA
V _{CC} Zener Voltage	I _{CC} = 25 mA	-	34	0,-	V
Undervoltage Lockout Section			,C)	>	
Start Threshold	-	7.8	8.4	9.0	V
Min. Operating Voltage	After Turn On	7.0	7.6	8.2	V

^{5.} These parameters, although guaranteed, are not 100% tested in production.

PACKAGE PIN DESCRIPTION

Package Lead Number			OB SELOPI
SO-8	SO-14	Lead Symbol	Function
1		СОМР	Error amp output, used to compensate error amplifier.
2	90	V_{FB}	Error amp inverting input.
3	9	SENSE	Noninverting input to Current Sense Comparator.
4	7	OSC	Oscillator timing network with capacitor to ground, resistor to $V_{\mbox{\scriptsize REF}}.$
5	8	GND	Ground.
-	9	Pwr GND	Output driver ground.
6	10	V _{оит}	Output drive pin.
-	11	V _{CC} Pwr	Output driver positive supply.
7	12	V _{CC}	Positive power suppy.
8	14	V _{REF}	Output of 5.0 V internal reference.
_	2, 4, 6, 13	NC	No Connection.

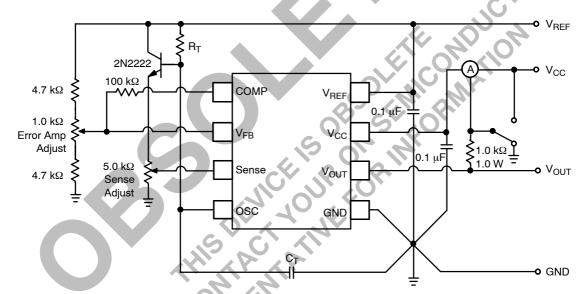
TYPICAL PERFORMANCE CHARACTERISTICS



100 90 80 70 60 50 40 30 20 10 400 500 700 1 k 0 ω ⊼ ⊼ 8 $R_T(\Omega)$

Figure 2. Oscillator Frequency vs C_T

Figure 3. Oscillator Duty Cycle vs R_T



CIRCUIT DESCRIPTION Figure 4. Test Circuit Open Loop Laboratory Test Fixture

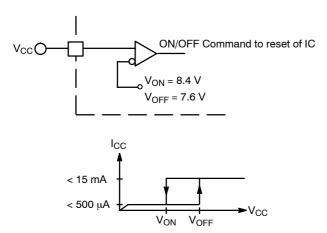


Figure 5. Startup Voltage for the CS52843

Undervoltage Lockout

During Undervoltage Lockout (Figure 5), the output driver is biased to sink minor amounts of current. The output should be shunted to ground with a resistor to prevent activating the power switch with extraneous leakage currents.

PWM Waveform

To generate the PWM waveform, the control voltage from the error amplifier is compared to a current sense signal which represents the peak output inductor current (Figure 6). An increase in V_{CC} causes the inductor current slope to increase, thus reducing the duty cycle. This is an inherent feed–forward characteristic of current mode control, since the control voltage does not have to change during changes of input supply voltage.

When the power supply sees a sudden large output current increase, the control voltage will increase allowing the duty cycle to momentarily increase. Since the duty cycle tends to exceed the maximum allowed to prevent transformer saturation in some power supplies, the internal oscillator waveform provides the maximum duty cycle clamp as programmed by the selection of oscillator timing components.

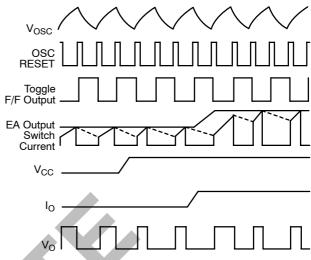


Figure 6. Timing Diagram

Setting the Oscillator

The times t_c and t_d can be determined as follows:

$$t_{\text{C}} = R_{T}C_{T}\text{In}\bigg(\frac{V_{REF} - V_{LOWER}}{V_{REF} - V_{UPPER}}\bigg)$$

$$t_d = R_T C_T ln \left(\frac{V_{REF} - I_d R_T V_{LOWER}}{V_{REF} - I_d R_T - V_{UPPER}} \right)$$

Substituting in typical values for the parameters in the above formulas:

$$V_{REF} = 5.0 \text{ V}, V_{UPPER} = 2.7 \text{ V},$$

 $V_{LOWER} = 1.0 \text{ V}, I_{d} = 8.3 \text{ mA}$

then

$$t_C \approx 0.5534RTCT$$

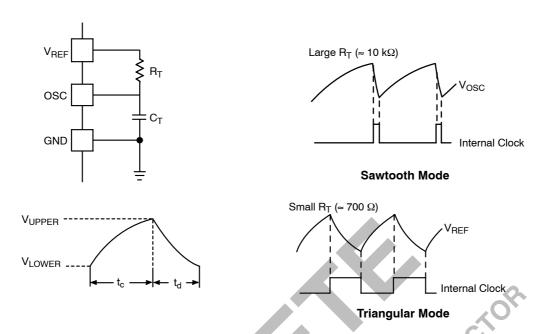
$$t_{d} = R_{T}C_{T} \ln \left(\frac{2.3 - 0.0083R_{T}}{4.0 - 0.0083R_{T}} \right)$$

For better accuracy R_T should be $\geq 10 \text{ k}\Omega$.

Grounding

High peak currents associated with capacitive loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to GND in a single point ground.

The transistor and 5.0 k Ω potentiometer are used to sample the oscillator waveform and apply an adjustable ramp to Sense.

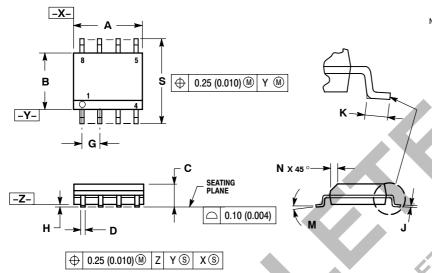


 V_{IN}

Figure 7. Oscillator Timing Network and Parameters

PACKAGE DIMENSIONS

SO-8 DF SUFFIX CASE 751-07 **ISSUE W**



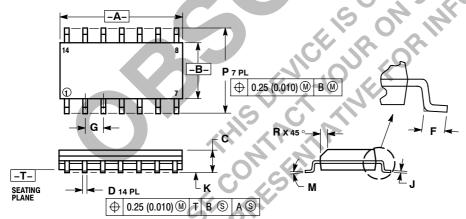
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN
 EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

		ls.				
		MILLIMETERS		INC	HES	
4	DIM	MIN	MAX	MIN	MAX	
	Α	4.80	5.00	0.189	0.197	
ľ	В	3.80	4.00	0.150	0.157	
	С	1.35	1.75	0.053	0.069	
	D	0.33	0.51	0.013	0.020	
	G	1.27	7 BSC	0.050 BSC		
	Н	0.10	0.25	0.004	0.010	
	J	0.19	0.25	0.007	0.010	
	<u></u> Κ	0.40	1.27	0.016	0.050	
d	M	0.0	8 °	0 °	8 °	
	N	0.25	0.50	0.010	0.020	
Ы	9	E 00	6.00	0.220	0.044	



ISSUE F



- (OTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMEAR.
- PECENSIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

PACKAGE THERMAL DATA

Parameter		SO-8	SO-14	Unit
$R_{\Theta JC}$	Typical	45	30	°C/W
$R_{\Theta JA}$	Typical	165	125	°C/W



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